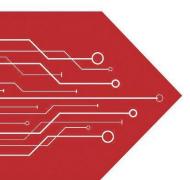
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Product data sheet

www.msksemi.com





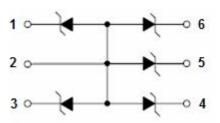
Features

- Small SOT-363 SMT Package
- Peak Power Dissipation 100W @8 x 20 us Pulse
- Low Leakage Current < 1uA @3 Volts
- Fast Response Time < 1 ns
- Low Capacitance
- ESD Protection to IEC 61000-4-2 Level 4
- RoHS Compliant in Lead-Free Versions

SOT363

Applications

- Instrumentation Equipement
- Serial and Parallel Ports
- Microprocessor Based Equipment
- Notebooks, Desktops, Servers



Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

P/N	V _{RWM} (V)	I _R (uA) @ V _{RWM}	V _{BR} (V) @ 1 mA		V _c (V) @ 5A	Capacitance @ OV Bias(pF)(note 2)		
	Max	Max	Min	Nom	Max	Max	Тур	Max
SMF05CT1G-MS	5	5.0	6.1	6.6	7.2	9.8		110

Absolute Maximum Ratings

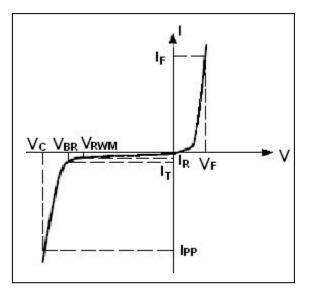
Abootato maximam ratingo				
Parameter	Symbol	Value	Units	
Peak Power Dissipation (Note 1.) @T _L = 25°C	P _{PK}	100	W	
Maximum Junction Temperature	T _{Jmax}	150	°C	
Operating Junction Temperature Range	TJ	-55 to 150	°C	
Storage Temperature Range	T _{STG}	-55 to 150	°C	



Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

•	·
Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ IPP
V_{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
I _T	Test Current
V_{BR}	Breakdown Voltage @ I _⊺
I _F	Forward Current
V _F	Forward Voltage @ I _F



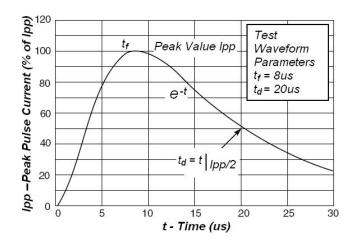


Fig1. Pulse Waveform

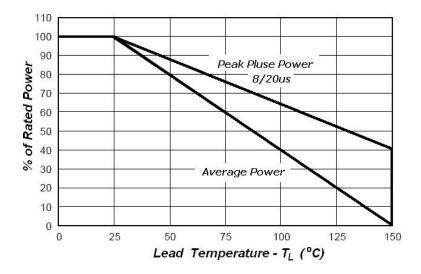
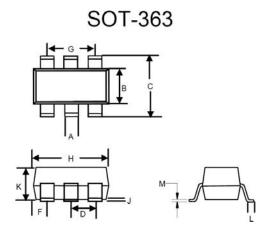


Fig2. Power Derating



Package Dimensions



DIMENSIONS					
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.004	.012	0.10	0.30	
В	.045	.053	1.15	1.35	
С	.079	.087	2.00	2.20	
D	.026		0.65Nominal		
F	.012	.016	0.30	0.40	
Н	.071	.087	1.80	2.20	
J		.004		0.10	
K	.035	.039	0.90	1.00	2
L	.010	.016	0.25	0.40	
М	.004	.016	0.10	0.25	

REEL SPECIFICATION

P/N	PKG	QTY
SMF05CT1G-MS	SOT-363	3000



Semiconductor

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